

Supplementary information

Colossal negative magnetoresistance from hopping in insulating ferromagnetic semiconductors

Xinyu Liu, Logan Riney, Josue Guerra, William Powers, Jiashu Wang, Jacek K. Furdyna and Badih A. Assaf

Department of Physics and Astronomy, University of Notre Dame, Notre Dame, IN 46556, USA

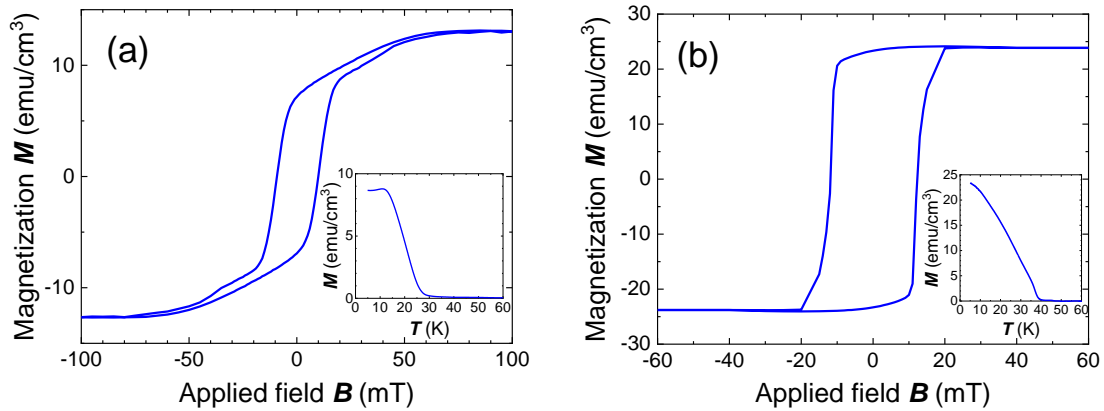


Fig. S1 Hysteresis loops measured at $T = 5$ K with magnetic field applied along out-of-plane [001] axis for two $\text{Ga}_{1-x}\text{Mn}_x\text{As}_{0.79}\text{P}_{0.21}$ samples with Mn concentrations x of (a) 4% and (b) 6%, respectively. Inset: Corresponding temperature dependences of magnetization measured along out-of-plane [001] axis for each sample.

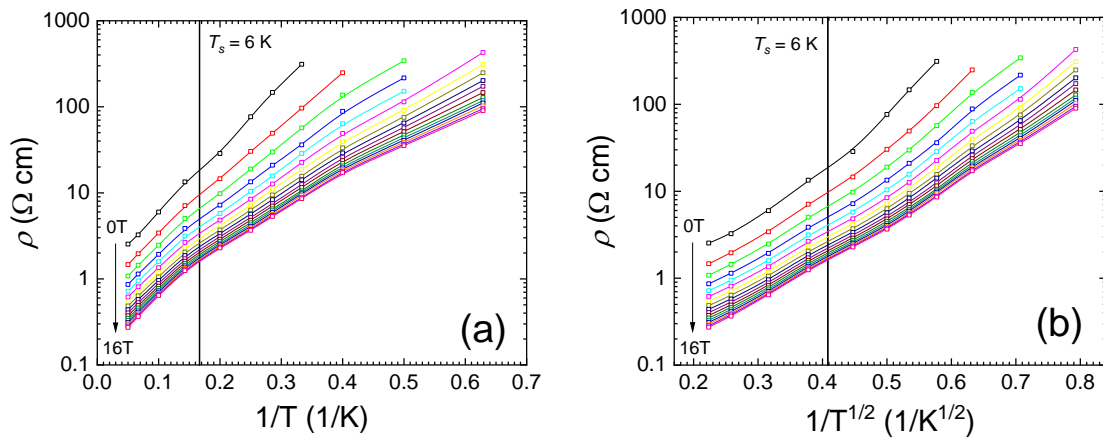


Fig. S2 Resistivity measured at various temperatures with magnetic field applied along out-of-plane [001] axis for $\text{Ga}_{0.96}\text{Mn}_{0.04}\text{As}_{0.79}\text{P}_{0.21}$ sample. (a) Scaling of resistivity versus $1/T$ at different magnetic fields. (b) Scaling of resistivity versus $1/T^{1/2}$ at different magnetic fields.

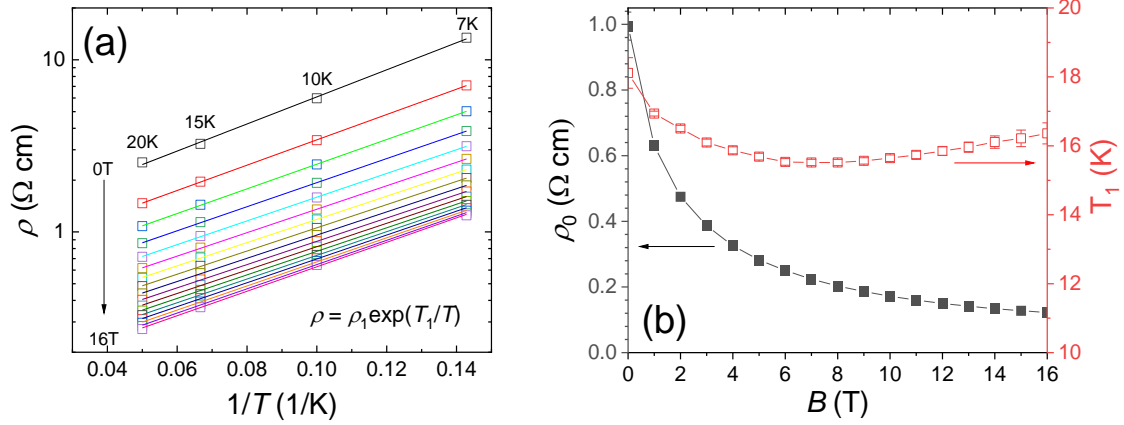


Fig. S3 (a) Scaling of resistivity versus $1/T$ at different magnetic fields for higher temperatures for $\text{Ga}_{0.96}\text{Mn}_{0.04}\text{As}_{0.79}\text{P}_{0.21}$ sample. The curves are fits of Eq. (1). (b) Field dependences of fitting parameters ρ_1 and T_1 .

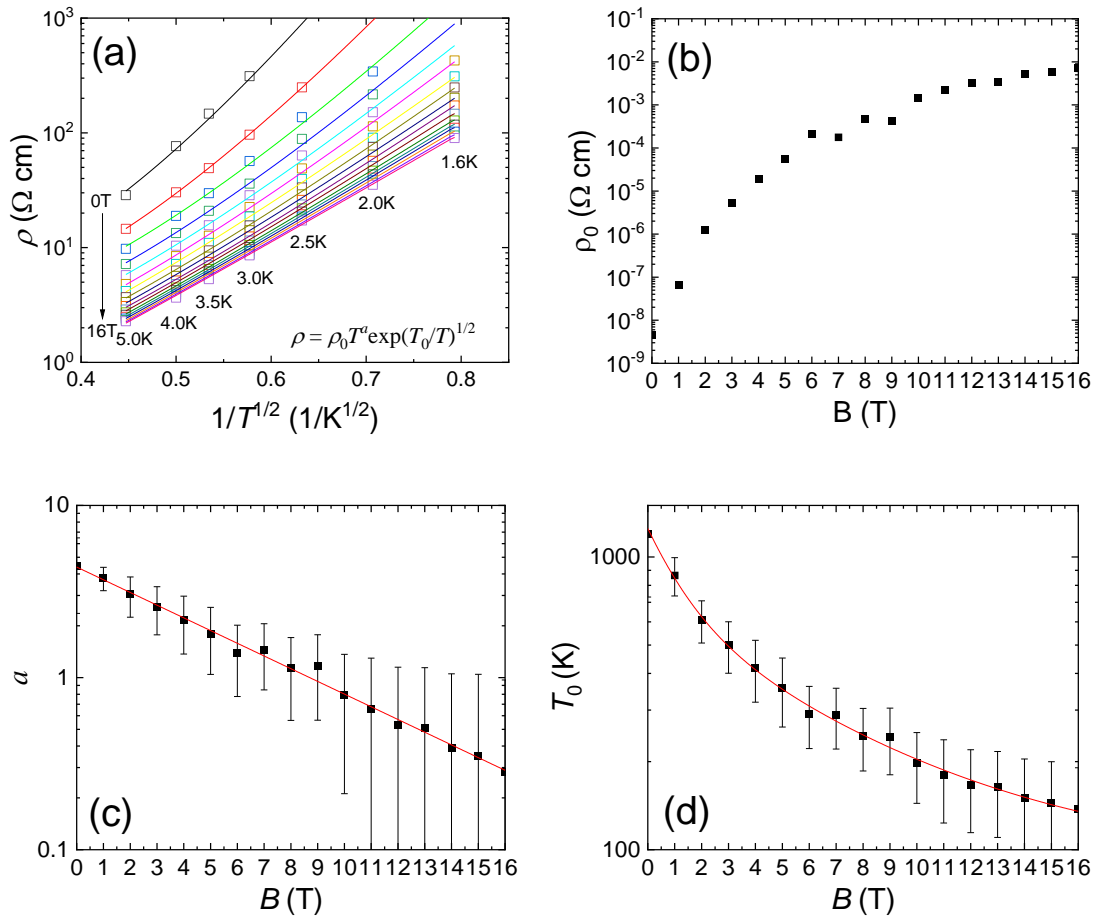


Fig. S4 Resistivity measured at various temperatures with magnetic field applied along out-of-plane [001] axis for $\text{Ga}_{1-x}\text{Mn}_x\text{As}_{0.79}\text{P}_{0.21}$ sample with Mn x of 4%. (a) Scaling of resistivity versus $T^{-1/2}$ at different magnetic fields for lower temperatures. The curves are fits of Eq. (3); (c) and (d)

show field dependence of fitting parameters α and T_0 . The red curve in (c) is a fit of an exponential decay. The red curve in (d) is a fit of a double exponential decay function.

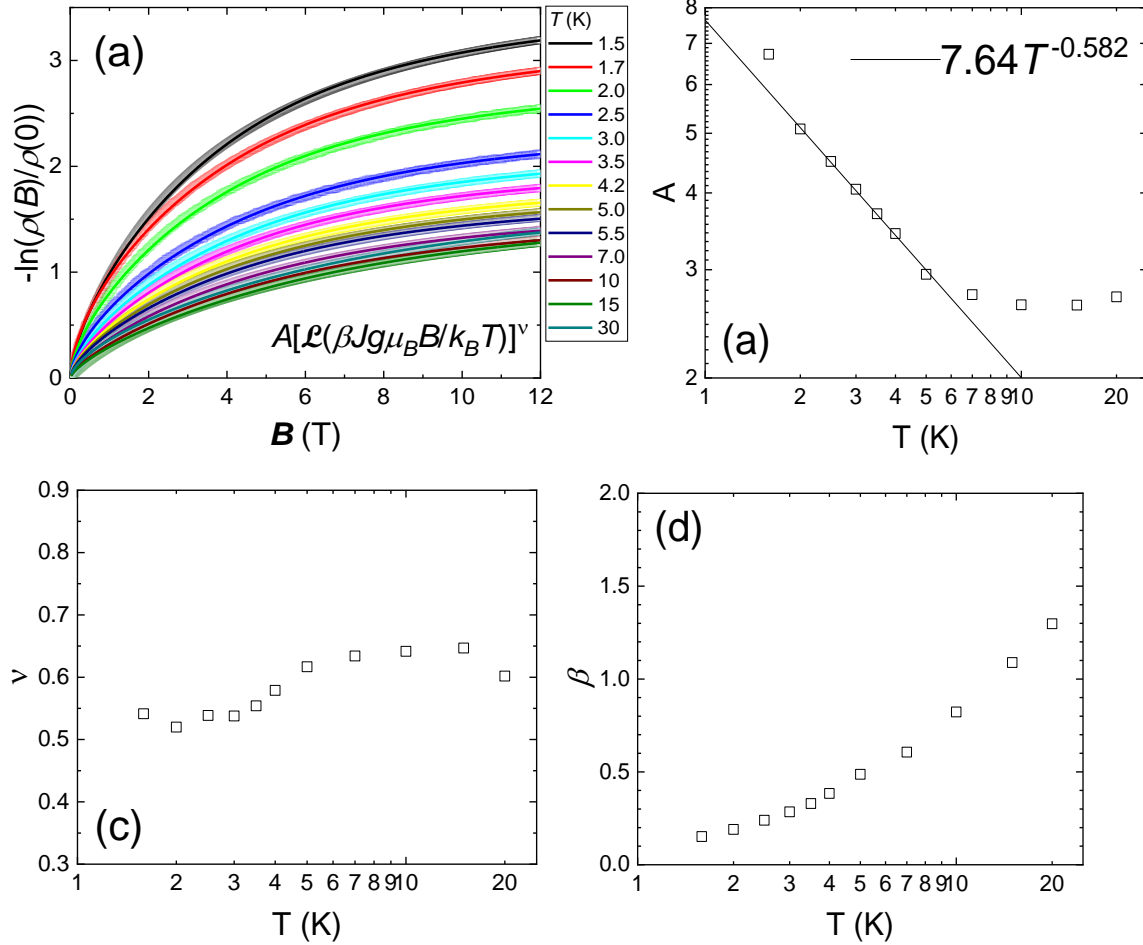


Fig. S5 (a) shows field dependence of $-\ln(\rho(B)/\rho(0))$ for $\text{Ga}_{0.94}\text{Mn}_{0.06}\text{As}_{0.79}\text{P}_{0.21}$ film at various temperatures below Curie temperature. The fits show as solid curves using Langevin equation $A(T)L(\beta J g \mu_B B / k_B T)^\nu$, where $L(x)$ is a modified Langevin function $L(x) = \coth(x) - 1/x$, $x = \beta J g \mu_B B / k_B T$; $J = 5/2$ is the angular moments of Mn ion, $g = 2.0$ is the g -factor, μ_B is the Bohr magneton, k_B is the Boltzmann constant and β is a rescale factor of spin system. (b, c, d) The fitting parameters A , ν , and β as function of temperature.

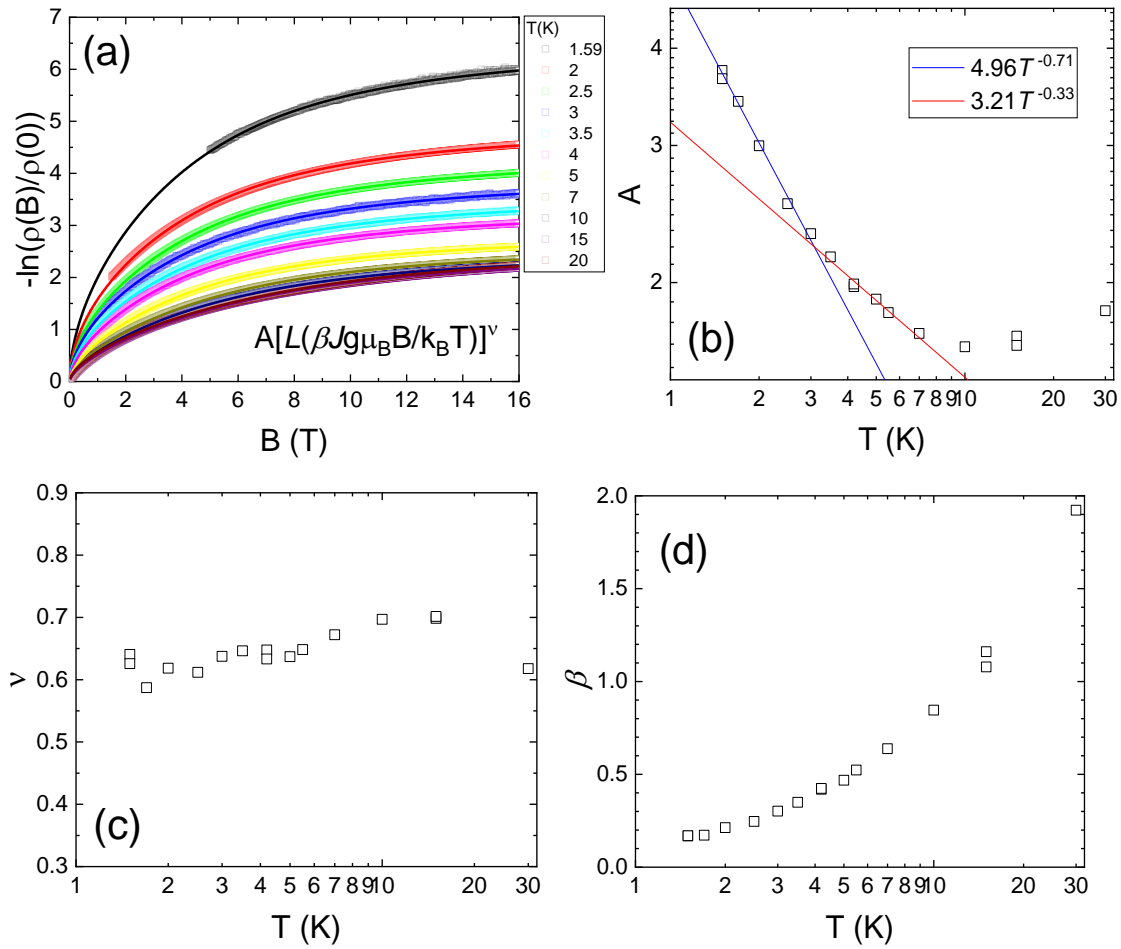


Fig. S6 (a) shows the field dependence of $-\ln(\rho(B)/\rho(0))$ for $\text{Ga}_{0.96}\text{Mn}_{0.04}\text{As}_{0.79}\text{P}_{0.21}$ film at various temperatures below Curie temperature. The fits show as solid curves. using Langevin equation $A(T)L(\beta J g \mu_B B / k_B T)^\nu$. (b, c, d) The Fitting parameters A , ν , and β as a function of temperature.